MOSPEC

MBR20150PT

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175℃ junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

SCHOTTKY BARRIER RECTIFIERS

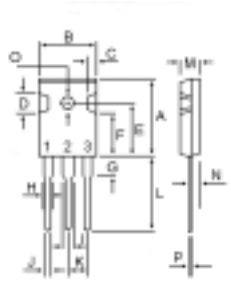
20 AMPERES
150 VOLTS

TO-3P

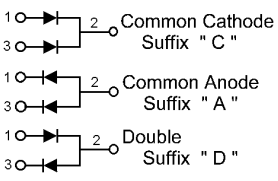
Features

- ⁎Low Forward Voltage.
- ⁎Low Switching noise.
- ⁎High Current Capacity
- ⁎Guarantee Reverse Avalanche.
- ⁎Guard-Ring for Stress Protection.
- ⁎Low Power Loss & High efficiency.
- ⁎175℃ Operating Junction Temperature
- ⁎Low Stored Charge Majority Carrier Conduction.
- ⁎Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- ⁎ESD: 4KV(Min.) Human-Body Model

⁎*In compliance with EU RoHs 2002/95/EC directives*



DIM	MILLIMETERS	
	MIN	MAX
A	20.63	22.38
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.81	15.22
F	11.72	12.84
G	4.20	4.50
H	1.82	2.46
I	2.92	3.23
J	0.89	1.53
K	5.26	5.66
L	18.50	21.50
M	4.68	5.36
N	2.40	2.80
O	3.25	3.65
P	0.55	0.70



MAXIMUM RATINGS

Characteristic	Symbol	MBR20150PT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	150	V
RMS Reverse Voltage	$V_{R(RMS)}$	105	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C=125℃	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	150	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +175	℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta jc}$	3.0	℃/w

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	MBR20150PT	Unit
Maximum Instantaneous Forward Voltage (I_F =10 Amp T_C = 25℃) (I_F =10 Amp T_C = 125℃)	V_F	0.95 0.85	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	0.01 10	mA

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FIG-1 FORWARD CURRENT DERATING CURVE

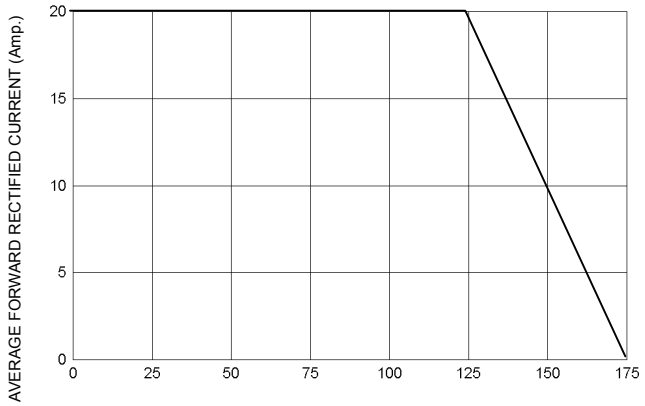

FIG-2 TYPICAL FORWARD CHARACTERISITICS

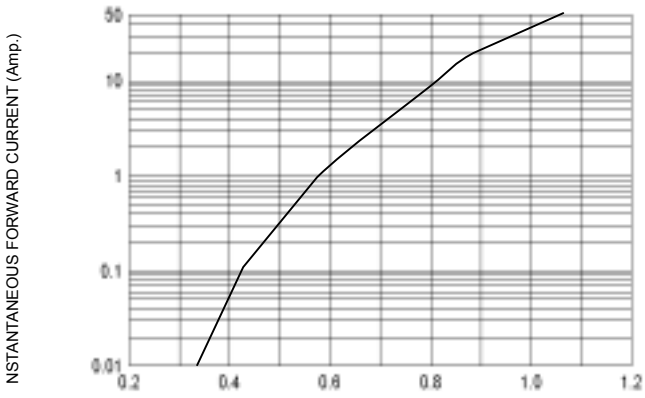

FIG-3 TYPICAL REVERSE CHARACTERISTICS

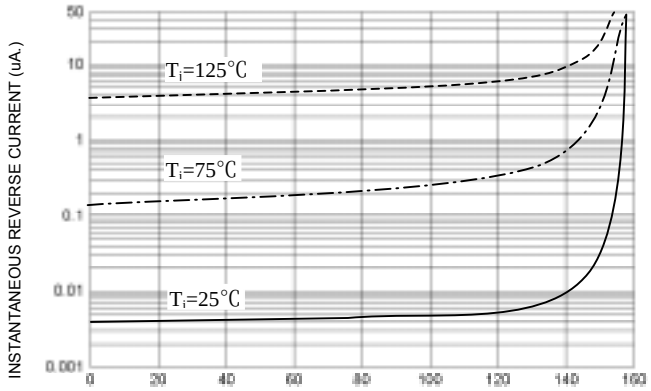

FIG-4 TYPICAL JUNCTION CAPACITANCE

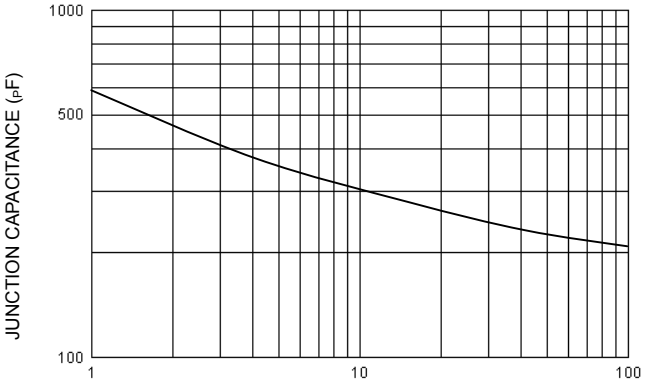

FIG-5 PEAK FORWARD SURGE CURRENT